

SLIC Subscriber Line Interface Circuit

The Intersil SLIC incorporates many of the BORSHT function on a single IC chip. This includes DC battery feed, a ring relay driver, supervisory and hybrid functions. This device is designed to maintain transmission performance in the presence of externally induced longitudinal currents. Using the unique Intersil dielectric isolation process, the SLIC can operate directly with a wide range of station battery voltages.

The SLIC also provides selective denial of power. If the PBX system becomes overloaded during an emergency, the SLIC will provide system protection by denying power to selected subscriber loops.

The Intersil SLIC is ideally suited for the design of new digital PBX systems, by eliminating bulky hybrid transformers.

Ordering Information

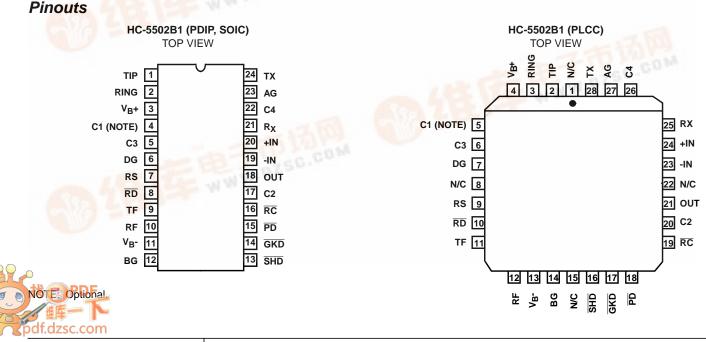
PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
HC <mark>3-5502B1-</mark> 5	0 to 75	24 Ld PDIP	E24.6
HC4P5502B1-5	0 to 75	28 Ld PLCC	N28.45
HC9P5502B1-5	0 to 75	24 Ld SOIC	M24.3

Features

- Low Cost Version of HC-5502B
- Capable of 12V or 5V (V_B+) Operation
- Monolithic Integrated Device
- DI High Voltage Process
- Compatible With Worldwide PBX Performance Requirements
- Controlled Supply of Battery Feed Current for Short Loops (30mA)
- Internal Ring Relay Driver
- Low Power Consumption During Standby
- Switch Hook, Ground Key and Ring Trip Detection
 Functions
- Selective Denial of Power to Subscriber Loops

Applications

- Solid State Line Interface Circuit for Analog and Digital PBX Systems
- Direct Inward Dial (DID) Trunks
- Voice Messaging PBXs
- Related Literature
 - AN549, The HC-5502S/4X Telephone Subscriber Line Interface Circuits (SLIC)
 - AN571, Using Ring Sync with HC-5502A and HC-5504 SLICs



Absolute Maximum Ratings (Note 1)

Supply Voltage

-60 to 0.5V
-0.5 to 15V
75V
0.5 to 15V
•

Operating Conditions

Thermal Information

Thermal Resistance (Typical, Note 2)	θ_{JA} (^o C/W)
24 Lead PDIP	65
24 Lead SOIC	75
28 Lead PLCC	65
Maximum Junction Temperature Plastic	150 ⁰ C
Maximum Storage Temperature Range65	5 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s)	300 ⁰ C
(SOIC and PLCC - Lead Tips Only)	

Die Characteristics

Transistor Count
Diode Count
Die Dimensions
Substrate Potential
Process Bipolar-DI

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 1. Absolute maximum ratings are limiting values, applied individually, beyond which the serviceability of the circuit may be impaired. Functional operability under any of these conditions is not necessarily implied.
- 2. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications

Unless Otherwise Specified, V_B- = -48V, V_B+ = 12V and 5V, AG = BG = DG = 0V, Typical Parameters T_A = 25^oC. Min-Max Parameters are Over Operating Temperature Range

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
On Hook Power Dissipation	I _{LONG} = 0 (Note 4), V _B + = 12V	-	135	235	mW
Off Hook Power Dissipation	$R_L = 600\Omega$, $I_{LONG} = 0$ (Note 4), V_B + = 12V	-	450	690	mW
Off Hook I _B +	$R_L = 600\Omega$, $I_{LONG} = 0$ (Note 4), $T_A = -40^{\circ}C$	-	-	6.0	mA
Off Hook I _B +x	$R_L = 600\Omega$, $I_{LONG} = 0$ (Note 4), $T_A = 25^{\circ}C$	-	-	5.3	mA
Off Hook I _B -	$R_L = 600\Omega$, $I_{LONG} = 0$ (Note 4)	-	-	39	mA
Off Hook Loop Current	R _L = 1200Ω, I _{LONG} = 0 (Note 4)	-	21	-	mA
Off Hook Loop Current	R _L = 1200Ω, V _B - = -42V, I _{LONG} = 0 (Note 4), T _A = 25^{o} C	17.5	-	-	mA
Off Hook Loop Current	R _L = 200Ω, I _{LONG} = 0 (Note 4)	25.5	30	34.5	mA
Fault Currents					
TIP to Ground		-	14	-	mA
RING to Ground		-	47	-	mA
TIP to RING		-	30	-	mA
TIP and RING to Ground		-	47	-	mA
Ring Relay Drive V _{OL}	$I_{OL} = 62 \text{mA}$	-	0.2	0.5	V
Ring Relay Driver Off Leakage	$V_{RD} = 12V, \overline{RC} = 1 = HIGH, T_A = 25^{\circ}C$	-	-	100	μΑ
Ring Trip Detection Period	$R_{L} = 600\Omega, T_{A} = 25^{\circ}C$	-	2	3	Ring Cycles
Switch Hook Detection Threshold	$\overline{SHD} = V_{OL}$	10	-	-	mA
	SHD = V _{OH}	-	-	5	mA
Ground Key Detection Threshold	$\overline{\text{GKD}} = \text{V}_{\text{OL}}$	20	-	-	mA
	$\overline{\text{GKD}} = \text{V}_{\text{OH}}$	-	-	10	mA
Loop Current During Power Denial	R _L = 200Ω	-	±2	-	mA
Dial Pulse Distortion		0	-	5	ms

Electrical Specifications

Unless Otherwise Specified, V_B - = -48V, V_B + = 12V and 5V, AG = BG = DG = 0V, Typical Parameters $T_A = 25^{0}$ C. Min-Max Parameters are Over Operating Temperature Range **(Continued)**

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Receive Input Impedance	(Note 3)	-	110	-	kΩ
Transmit Output Impedance	(Note 3)	-	10	20	Ω
Two Wire Return Loss SRL LO	Referenced to 600Ω +2.16µF (Note 3)	-	15.5	-	dB
ERL		-	24	-	dB
SRL HI		-	31	-	dB
Longitudinal Balance 2-Wire Off Hook	1V _{RMS} 200Hz - 3400Hz, (Note 3) IEEE Method	53	58	-	dB
2-Wire On Hook	$- 0^{\circ}C \le T_{A} \le 75^{\circ}C$	53	58	-	dB
4-Wire Off Hook		50	58	-	dB
Low Frequency Longitudinal Balance	R.E.A. Method, (Note 3)	-	-	23	dBrnC
	$\begin{array}{l} R_L = 600\Omega, \\ 0^0C \leq T_A \leq 75^0C \end{array}$	-	-	-67	dBm0p
Insertion Loss 2-Wire to 4-Wire, 4-Wire to 2-Wire	At 1kHz, 0dBm Input Level, Referenced 600Ω	-	±0.05	±0.2	dB
Frequency Response	200 - 3400Hz Referenced to Absolute Loss at 1kHz and 0dBm Signal Level (Note 3)	-	±0.02	±0.05	dB
Idle Channel Noise	(Note 3)	-	1	5	dBrnC
2-Wire to 4-Wire, 4-Wire to 2-Wire		-	-89	-85	dBm0p
Absolute Delay 2-Wire to 4-Wire, 4-Wire to 2-Wire	(Note 3)	-	-	2	μs
Trans Hybrid Loss	Balance Network Set Up for 600Ω Termination at 1kHz	30	40	-	dB
Overload Level	V _B + = 5V	1.5			V _{PEAK}
2-Wire to 4-Wire, 4-Wire to 2-Wire	V _B + = 12V	1.75	-	-	V _{PEAK}
Level Linearity 2-Wire to 4-Wire, 4-Wire to 2-Wire	At 1kHz, (Note 3) Referenced to 0dBm Level +3 to -40dBm	-	-	±0.05	dB
	-40 to -50dBm	-	-	±0.1	dB
	-50 to -55dBm	-	-	±0.3	dB
Power Supply Rejection Ratio V _B + to 2-Wire	(Note 3) 30 - 60Hz	15	-	-	dB
V _B + to Transmit	$R_{L} = 600\Omega$	15	-	-	dB
V _B - to 2-Wire	1	15	-	-	dB
V _B - to Transmit	7	15	-	-	dB
V _B + to 2-Wire	200 - 16kHz	30	-	-	dB
V _B + to Transmit	$R_L = 600\Omega$	30	-	-	dB
V _B - to 2-Wire		30	-	-	dB
V _B - to Transmit		30	-	-	dB
Logic Input Current (RS, RC, PD)	$0V \le V_{IN} \le 5V$	<u> </u>	-	±100	μA

Electrical Specifications

Unless Otherwise Specified, $V_{B^-} = -48V$, $V_B + = 12V$ and 5V, AG = BG = DG = 0V, Typical Parameters $T_A = 25^{\circ}C$. Min-Max Parameters are Over Operating Temperature Range **(Continued)**

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Logic Inputs					
Logic '0' V _{IL}		-	-	0.8	V
Logic '1' V _{IH}		2.0	-	5.5	V
Logic Outputs					
Logic '0' V _{OL}	$I_{LOAD} 800\mu A, V_{B}+ = 12V, 5V$	-	0.1	0.5	V
Logic '1' V _{OH}	I _{LOAD} 80μA, V _B + = 12V	2.7	5.0	5.5	V
	I_{LOAD} 40 μ A, V_{B} + = 5V	2.7	-	5.0	V

Uncommitted Op Amp Specifications

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Input Offset Voltage		-	±5	-	mV
Input Offset Current		-	±10	-	nA
Input Bias Current		-	20	-	nA
Differential Input Resistance	(Note 3)	-	1	-	MΩ
Output Voltage Swing	$R_{L} = 10k\Omega, V_{B} + = 12V$	-	±6.2	±6.6	V _{PEAK}
	$R_{L} = 10k\Omega, V_{B} + = 5V$	-	±3	-	V _{PEAK}
Output Resistance	A _{VCL} = 1 (Note 3)	-	10	-	Ω
Small Signal GBW	(Note 3)	-	1	-	MHz

NOTES:

3. These parameters are controlled by design or process parameters and are not directly tested. These parameters are characterized upon initial design release, upon design changes which would affect these characteristics, and at intervals to assure product quality and specification compliance.

4. I_{LONG} = Longitudinal Current.

Pin Descriptions

28 PIN PLCC	24 PIN DIP/SOIC	SYMBOL	DESCRIPTION
2	1	TIP	An analog input connected to the TIP (more positive) side of the subscriber loop through a 150Ω feed resistor and a ring relay contact. Functions with the Ring terminal to receive voice signals from the telephone and for loop monitoring process.
3	2	RING	An analog input connected to the RING (more negative) side of the subscriber loop through a 150Ω feed resistor and a ring relay contact. Functions with the Tip terminal to receive voice signals from the telephone and for loop monitoring purposes.
4	3	V _B +	Positive Voltage Source - Most positive supply. V _B + is typically 12V or 5V.
5	4	C ₁	Capacitor #1 - Optional Capacitor used to improve power supply rejection. This pin should be left open if un- used.
6	5	C ₃	Capacitor #3 - An external capacitor to be connected between this terminal and analog ground. Required for proper operation of the loop current limiting function, and for filtering V_B - supply. Typical value is 0.3μ F, 30V.
7	6	DG	Digital Ground - To be connected to zero potential and serves as a reference for all digital inputs and out- puts on the SLIC.
9	7	RS	Ring Synchronization Input - A TTL - Compatible Clock Input. The clock should be arranged such that a positive transition occurs on the negative going zero crossing of the ring voltage source, ensuring that the ring relay is activated and deactivated when the instantaneous ring voltage is near zero. If synchronization is not required, tie to 5V.
10	8	RD	Relay Driver - A low active open collector logic output. When enabled, the external ring relay is energized.
11	9	TF	Tip Feed - A low impedance analog output connected to the TIP terminal through a 150Ω feed resistor. Functions with the RF terminal to provide loop current, feed voice signals to the telephone set, and sink longitudinal current.
12	10	RF	Ring Feed - A low impedance analog output connected to the RING terminal through a 150Ω feed resistor. Functions with the TF terminal to provide loop current, feed voice signal to the telephone set, and sink longitudinal current.
13	11	V _B -	Negative Voltage Source - Most negative supply. V_B - is typically -48V with an operational range of -42V to -58V. Frequently referred to as "battery".
14	12	BG	Battery Ground - To be connected to zero potential. All loop current and some quiescent current flows into this ground terminal.
16	13	SHD	Switch Hook Detection - A Low Active LS TTL - Compatible Logic Output. This output is enabled for loop currents exceeding 10mA and disabled for loop currents less than 5mA.
17	14	GKD	Ground Key Detection - A Low Active LS TTL - Compatible Logic Output. This output is enabled if the DC current into the ring lead exceeds the DC current out of the tip lead by more than 20mA, and disabled it this current difference is less than 10mA.
18	15	PD	Power Denial - A Low Active TTL - Compatible Logic Input. When enabled the switch hook detect (SHD) and ground key detect (GKD) are not necessarily valid, and the relay driver (RD) output is disabled.
19	16	RC	Ring Command - A Low Active TTL - Compatible Logic Input. When enabled, the relay driver (\overline{RD}) output goes low on the next rising edge of the ring sync (\overline{RS}) input, as long as the SLIC is not in the power denia state $(\overline{PD} = 0)$ or the subscriber is not already off- hook $(\overline{SHD} = 0)$.
20	17	C ₂	Capacitor #2 - An external capacitor to be connected between this terminal and digital ground. Prevents false ground key indications from occurring during ring trip detection. Typical value is 0.15µF, 10V. This capacitor is not used if ground key function is not required.
21	18	OUT	The analog output of the spare operational amplifier.
23	19	-IN	The inverting analog input of the spare operational amplifier.
24	20	+IN	The non-inverting analog input of the spare operational amplifier.
25	21	RX	Receive Input, Four Wire Side - A high impedance analog input which is internally biased. Capacitive coupling to this input is required. AC signals appearing at this input differentially drive the Tip feed and Ring feed amplifiers, which in turn drive tip and ring through 300Ω of feed resistance on each side of the line.

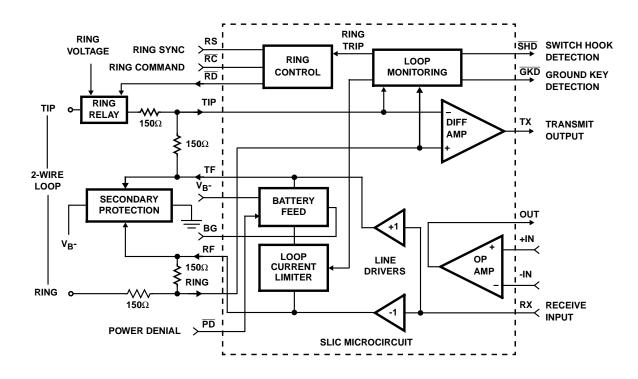
28 PIN PLCC	24 PIN DIP/SOIC	SYMBOL	DESCRIPTION
26	22	C ₄	Capacitor #4 - An external capacitor to be connected between this terminal and analog ground. This ca- pacitor prevents false ground key indication and false ring trip detection from occurring when longitudinal currents are induced onto the subscriber loop from nearby power lines and other noise sources. This ca- pacitor is also required for the proper operation of ring trip detection. Typical value is 0.5µF to 1.0µF, 20V. This capacitor should be nonpolarized.
27	23	AG	Analog Ground - To be connected to zero potential and serves as a reference for the transmit output (TX) and receive input (RX) terminals.
28	24	ТХ	Transmit Output, Four Wire Side - A low impedance analog output which represents the differential volt- age across Tip and Ring. Transhybrid balancing must be performed (using the SLIC microcircuit's spare op amp) beyond this output to completely implement two to four wire conversion. This output is unbal- anced and referenced to analog ground. Since the DC level of this output varies with loop current, capac- itive coupling to the next stage is essential.
1, 8, 5, 22		NC	No Internal Connection.

Pin Descriptions (Continued)

NOTE:

5. All grounds (AG, BG, and DG) must be applied before V_B+ or V_B-. Failure to do so may result in premature failure of the part. If a user wishes to run separate grounds off a line card, the AG must be applied first.

Functional Diagram



HC-5502B1

SLIC FUNCTIONAL SCHEMATIC

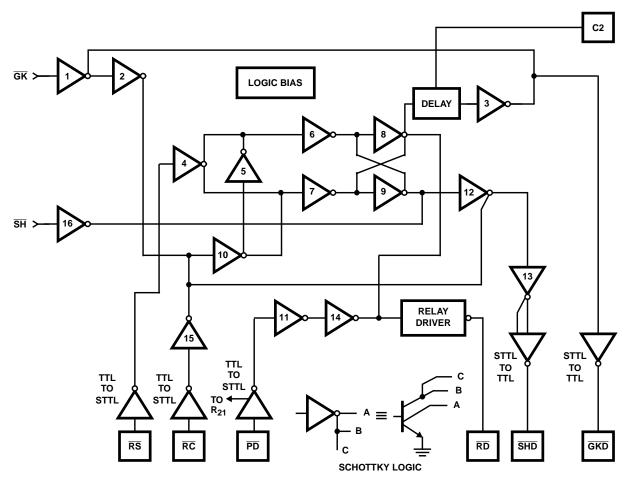
Schematic

PIN NUMBERS FOR DIP/SOIC PACKAGE 21 22 12 23 3 4 20 19 18 11 6 BAT ANA DIG RCV C4 C1 OUT V_B+ -VBAT + GND GND V_B+ GND V_B+ \checkmark P Ь Ь 7 т • V_{B1} A-500 -0 V_{B2} OP AMP VOLTAGE AND CURRENT -• v_{B3} **BIAS NETWORK** - V_{B4} -0 V_{B5} -0 -5V 白 R₁₇ VBAT Y V_B+□ ₩**~**0 V_{B2} B1 182 183 184 185 186 187 188 VBAT 189 1810 1811 I_{B3} A-400 1 TF TIP FEED AMP **RING TRIP** ا₈₄ ه -5V IB10 VB+ R₁₂ DETECTOR \sim P R₇ 5V **口** V_B+ 1 TIP Ŵ A-200 GK R8 ₩ R₂₀ V_B+口 Q_{D3} Q_{D36} LONG'L GND SHORTS 亡 V_B⊿ I/V AMP R₁₀ VBAT CURRENT o LIMITING \sim I_{B8} R₁₁ I_{B7} γ ρl_{B1} R9 v_{ват} 품 ^{VB+}모 ~~/ GKD 14 R₅ ₩ VBAT Ŵ P R₃ ο ۲_{۷в} SWITCH HOOK Ŵ C2 17 IIL R4 2 RING DETECTOR 白 LOGIC A-100 VBAT TRANSV'L INTERFACE V_B+ R₁ I/VAMP SHD 13 SH R₂ Ц v_{ват} Ув1 Ŵ Γ Ι_{Β6} Ř₁₆ o RC 16 I_{B9} Ŵ R₁₅ 9 VBAT/2 REFERENCE Q_{D27} **Q**_{D28} Ŵ Ą THERMAL Ж V_{B2} H PD 15 LOOP CURRENT LIMITING LIMITING A-300 V_{B5} Ą RFC R₂₁ ο Ι_{Β2} 10 RF **RING FEED Ş**R18 ⊶≮ AMP V_{B5} Ċ. V_{BAT} Y **≶**R₁₉ I_{B5} 님 는 VBAT Ċ R₁₃ VBAT тх RD C3 RS 24

HC-5502B1

Logic Diagram





Overvoltage Protection and Longitudinal Current Protection

The SLIC device, in conjunction with an external protection bridge, will withstand high voltage lightning surges and power line crosses.

High voltage surge conditions are as specified in Table 1.

The SLIC will withstand longitudinal currents up to a maximum or $30mA_{RMS}$, $15mA_{RMS}$ per leg, without any performance degradation.

ΤА	BL	.E	1

PARAMETER	TEST CONDITION	PERFORMANCE (MAX)	UNITS
Longitudinal Surge	10μs Rise/ 1000μs Fall	±1000 (Plastic)	V _{PEAK}
Metallic Surge	10μs Rise/ 1000μs Fall	±1000 (Plastic)	V _{PEAK}
T/GND R/GND	10μs Rise/ 1000μs Fall	±1000 (Plastic)	V _{PEAK}
50/60Hz Current T/GND R/GND	11 Cycles Limited to 10A _{RMS}	700 (Plastic)	V _{RMS}

Applications Diagram

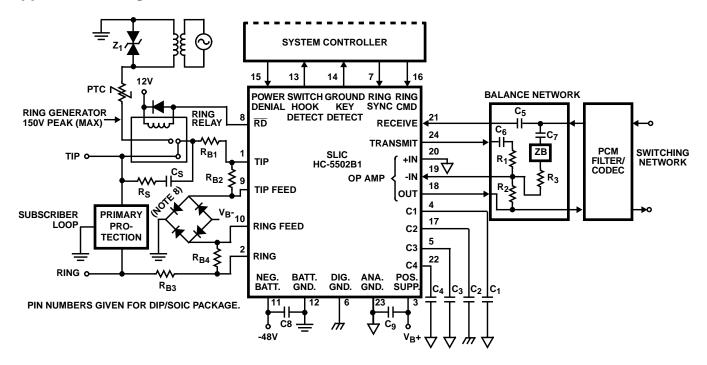


FIGURE 1. TYPICAL LINE CIRCUIT APPLICATION WITH THE MONOLITHIC SLIC

Typical Component Values

 $C_1 = 0.5 \mu F$ (Note 6).

C₂ = 0.15μF, 10V.

 $C_3 = 0.3 \mu F$, 30V.

 C_4 = 0.5 μF to 1.0 μF , 10%, 20V (Should be nonpolarized).

 $C_5 = 0.5 \mu F$, 20V.

 $C_6 = C_7 = 0.5 \mu F$ (10% Match Required) (Note 7), 20V.

 $C_8 = 0.01 \mu$ F, 100V.

 $C_9 = 0.01 \mu$ F, 20V, ±20%.

NOTES:

6. C_1 is an optional capacitor used to improve V_B + supply rejection. This pin must be left open if unused.

- 7. To obtain the specified transhybrid loss it is necessary for the three legs of the balance network, C₆-R₁ and R₂ and C₇-Z_B-R₃, to match in impedance to within 0.3%. Thus, if C₆ and C₇ are 1µF each, a 20% match is adequate. It should be noted that the transmit output to C₆ sees a -22V step when the loop is closed. Too large a value for C₆ may produce an excessively long transient at the op amp output to the PCM Filter/CODEC.
- 8. A 0.5μ F and $100k\Omega$ gives a time constant of 50ms. The uncommitted op amp output is internally clamped to stay within ±6.6V and is current limited.
- 9. Secondary protection diode bridge recommended is a 2A, 200V type.
- 10. All grounds (AG, BG, and DG) must be applied before V_B+ or V_B-. Failure to do so may result in premature failure of the part. If a user wishes to run separate grounds off a line card, the AG must be applied first.

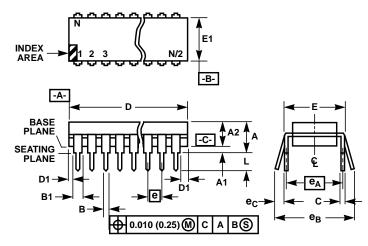
 $R_1 = R_2 = R_3 = 100 k\Omega$ (0.1% Match Required, 1% absolute value), $Z_B = 0$ for 600Ω Terminations (Note 7).

 $R_{B1} = R_{B2} = R_{B3} = R_{B4} = 150\Omega$ (0.1% Match Required, 1% absolute value).

 R_S = 1kΩ, C_S = 0.1µF, 200V typically, depending on V_{RING} and line length.

 $Z_1 = 150V$ to 200V transient protection. PTC used as ring generator ballast.

Dual-In-Line Plastic Packages (PDIP)



NOTES:

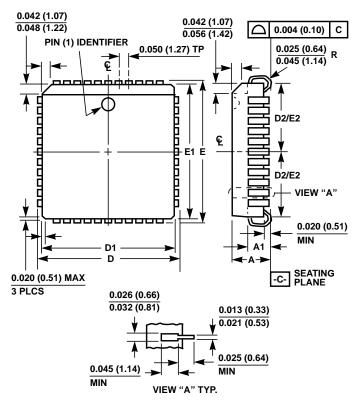
- 1. Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- 4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- 5. D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and e_A are measured with the leads constrained to be perpendicular to datum -C-.
- 7. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- 10. Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 0.045 inch (0.76 1.14mm).

E24.6 (JEDEC MS-011-AA ISSUE B) 24 LEAD DUAL-IN-LINE PLASTIC PACKAGE

	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
A	-	0.250	-	6.35	4
A1	0.015	-	0.39	-	4
A2	0.125	0.195	3.18	4.95	-
В	0.014	0.022	0.356	0.558	-
B1	0.030	0.070	0.77	1.77	8
С	0.008	0.015	0.204	0.381	-
D	1.150	1.290	29.3	32.7	5
D1	0.005	-	0.13	-	5
E	0.600	0.625	15.24	15.87	6
E1	0.485	0.580	12.32	14.73	5
е	0.100 BSC		2.54 BSC		-
e _A	0.600 BSC		15.24 BSC		6
eB	-	0.700	-	17.78	7
L	0.115	0.200	2.93	5.08	4
Ν	24		24		9

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Plastic Leaded Chip Carrier Packages (PLCC)



NOTES:

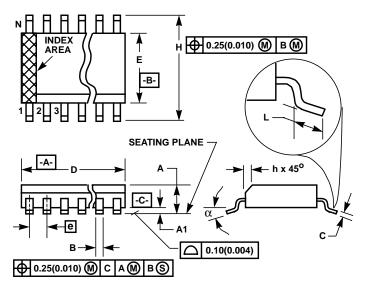
- 1. Controlling dimension: INCH. Converted millimeter dimensions are not necessarily exact.
- 2. Dimensions and tolerancing per ANSI Y14.5M-1982.
- Dimensions D1 and E1 do not include mold protrusions. Allowable mold protrusion is 0.010 inch (0.25mm) per side. Dimensions D1 and E1 include mold mismatch and are measured at the extreme material condition at the body parting line.
- 4. To be measured at seating plane -C- contact point.
- 5. Centerline to be determined where center leads exit plastic body.
- 6. "N" is the number of terminal positions.

N28.45 (JEDEC MS-018AB ISSUE A) 28 LEAD PLASTIC LEADED CHIP CARRIER PACKAGE

	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
A	0.165	0.180	4.20	4.57	-
A1	0.090	0.120	2.29	3.04	-
D	0.485	0.495	12.32	12.57	-
D1	0.450	0.456	11.43	11.58	3
D2	0.191	0.219	4.86	5.56	4, 5
E	0.485	0.495	12.32	12.57	-
E1	0.450	0.456	11.43	11.58	3
E2	0.191	0.219	4.86	5.56	4, 5
N	2	8	2	28	6

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Small Outline Plastic Packages (SOIC)



NOTES:

- 1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- 9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M24.3 (JEDEC MS-013-AD ISSUE C) 24 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE

	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
A	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
В	0.013	0.020	0.33	0.51	9
С	0.0091	0.0125	0.23	0.32	-
D	0.5985	0.6141	15.20	15.60	3
E	0.2914	0.2992	7.40	7.60	4
е	0.05 BSC		1.27 BSC		-
Н	0.394	0.419	10.00	10.65	-
h	0.010	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
N	24		24		7
α	0 ⁰	8 ⁰	0 ⁰	8 ⁰	-

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All Intersil semiconductor products are manufactured, assembled and tested under ISO9000 quality systems certification.

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